



# Bipolar PNP Bare Die – BTP6087

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## Part Description

The BTP6087 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

## Key Parameters:

- VCBO = -40V
- VCEO = -40V
- VEBO = -5V
- hFE = 90-365 @ VCE = -2V, IC = -0.15A
- VCE(Sat) = -0.75V @ IC = -0.5A, IB = -50mA
- fT = 200 MHz @ VCE = -20V, IE = 0A
- COBO = 10pF @ VCB = -10V

## Features

Low VCE(sat)

## Die Size (Unawn)

400µm X 400µm, 16 Mils X 16 Mils

This is a shortform datasheet only

For the full datasheet

Please contact [sales@siliconsupplies.com](mailto:sales@siliconsupplies.com)

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